NSN 5962-01-470-6317

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Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
55.0/+125.0 degrees celsius
Storage Tempurature Range:
65.0/+150.0 degrees celsius
Features Provided:
Monolithic and electrostatic sensitive and 3-state output
nclosure Material:
Ceramic and glass
nclosure Configuration:
Dual-in-line
Output Logic Form:
Bipolar metal-oxide semiconductor
Design Function And Quantity:
1 latch, d
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital, advanced bipolar cmos, octal transparent d- type latch with three-state outputs, ttl compatible inputs, monolithic silico
Voltage Rating And Type Per Characteristic:
0.5 volts input and 7.0 volts input
Special Features:
Generic p/n 54abt533
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 printed circuit
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
Yes - demil/mli
Filg:
A458a0